Chapter 8

Atomic Resolution -Scanning Transmission Electron Microscopy (STEM)

Evolution of resolution in EM





8.2 Convergent Beam Diffraction





parallel beam electron diffraction (ED)

convergent beam electron diffraction (CBED)







8.3 HAADF- STEM (High Angle Annual Dark Field)



STEM: Scanning a focused spot across the sample



8.4 thermal diffuse scattering (TDS)



Thermal diffuse scattering (TDS), which is a signal used to form the image in HAADF-STEM and which was previously considered as "background intensity," became a powerful source of information by using an HAADF detector.

8.5 Quantitative interpretation of HAADF-STEM imaging



STEM Images

- Elastic BF-STEM images are equivalent to TEM bright-field images (reciprocity principle). They are mainly produced Bragg disks hitting the detector. They contain diffraction contrast and are therefore very sensitive to strain/diffraction conditions in the material.
- High-angle annular dark-field STEM (HAADF-STEM) images are mainly produced by thermal diffuse scattering (TDS), because at high scattering angles TDS has the highest scattering cross section.
- (medium angle) ADF-STEM images contain both, Bragg diffraction and TDS contributions.

STEM-Image

The intensity of atom columns in HAADF-STEM imaging depends on the average atomic number Z of individual atom columns (app. proportional to the square). Atom columns with higher average atomic number Z exhibit higher intensity. STEM transfer function has no reversals!

Qualitative interpretation of HAADF-STEM images is relatively straightforward.

Quantitative interpretation of HAADF-STEM images, i.e. determination of the chemical composition of atom columns based on intensities, requires extensive image calculations and image matching.

STEM image signal

- STEM images are acquired sequentially, i.e. pixel by pixel. The precision of the image therefore depends on the reproducibility of the beam positioning.
- The emission current of some FEG sources (cold FEGs) may fluctuate. This leads to a **fluctuation** of counts between pixels.
- The signal recorded from the detector is usually amplified with an adjustable bias (threshold) and gain (amplification). This makes it often **impossible to quantify** the number of electrons per pixel in a given STEM image.
- Less than 10% of the incident electrons scatter to the HAADF detector (depends on detector geometry, of course). This makes HAADF images very noisy. However, the very high contrast of HAADF images compensates for some of the noise.

8.6 Comparison of HRTEM and HAADF



Phase Contrast

Amplitude Contrast

Aberration corrected TEM



Examples of STEM images

Example Pd particle on SrTiO3



BF-STEM image (contains diffraction contrast)

HAADF-STEM image (chemical sensitivity because of Z-contrast)

Quantum Well



Examples of STEM images

MAADF image of grain boundary in Ba_{6-3x}Nd_{8+2x}Ti₁₈O₅₄ (BNT)



Jožef Stefan Institute

Pd= NH

9-7:Guest = CCI,CO,Na 9-8: Guest = CBr,

SLONANO2007 October 10-12, 2007, IJS, Ljubljana



Beware of Beam Damage!

300kV, longer exposure

300kV, 1-2sec exposure

C. Kisielowski, NCEM Berkeley

Atomic resolution of EELS of La_{0.7}Sr_{0.3}MnO₃/SrTiO₃ multilayer



- D. A. Muller, et al, SCIENCE 319 1073-1075 (2008)

8.7 Atomic Resolution Spectrum Imaging



Atomic resolution compositional and bonding maps



8.8 STEM Tomography







Kinematic diffraction
Lens aberration can be ignored

Inverse Randon Transformation Tomographic Reconstruction

Fourier Projection-Slice Theorem



Micro-electronics







Flash device



8.8 STEM Tomography







Hydroxypyromorphite nanocrystallite whisker and pseudomorph formed on hydroxyapatite